



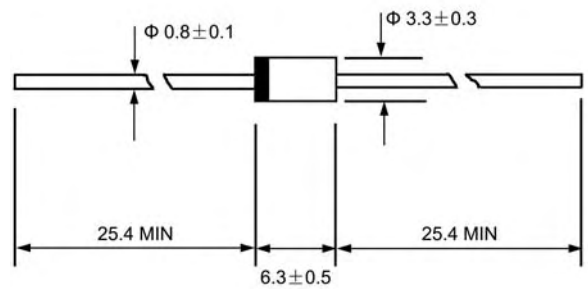
### DO - 15

### Features

- ◇ Low cost
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

### Mechanical Data

- ◇ Case: JEDEC DO--15, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL- STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.014 ounces, 0.39 grams
- ◇ Mounting position: Any



Dimensions in millimeters

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20% .

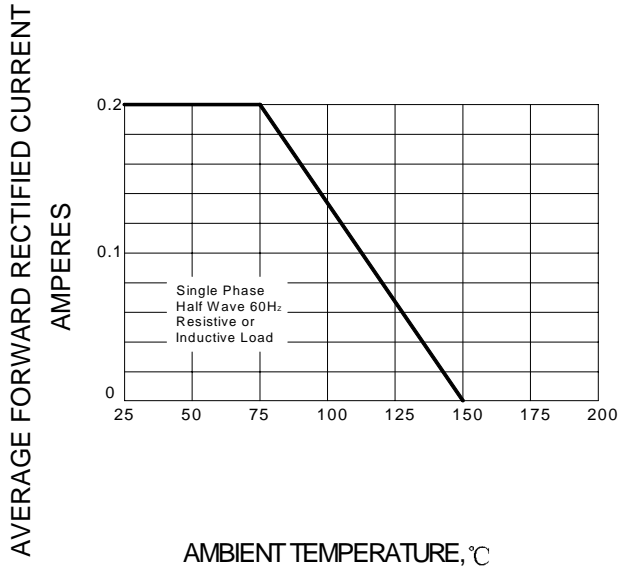
		R2500F	R3000F	R4000F	R5000F	UNITS
Maximum recurrent peak reverse voltage	$V_{RRM}$	2500	3000	4000	5000	V
Maximum RMS voltage	$V_{RMS}$	1750	2100	2800	3500	V
Maximum DC blocking voltage	$V_{DC}$	2500	3000	4000	5000	V
Maximum average forward rectified current 9.5mm lead length, @ $T_A=75^\circ C$	$I_{F(AV)}$	0.2				A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ C$	$I_{FSM}$	30.0				A
Maximum instantaneous forward voltage @ 0.2A	$V_F$	4.0	5.0	6.5		V
Maximum reverse current @ $T_A=25^\circ C$ at rated DC blocking voltage @ $T_A=100^\circ C$	$I_R$	5.0 100.0				$\mu A$
Maximum reverse recovery time (Note1)	$t_{rr}$	500				ns
Typical junction capacitance (Note2)	$C_J$	15				pF
Operating junction temperature range	$T_J$	- 55 ---- + 150				$^\circ C$
Storage temperature range	$T_{STG}$	- 55 ---- + 150				$^\circ C$

NOTE: 1. Measured with  $I_F=0.5A$ ,  $I_R=1A$ ,  $I_{rr}=0.25A$ .

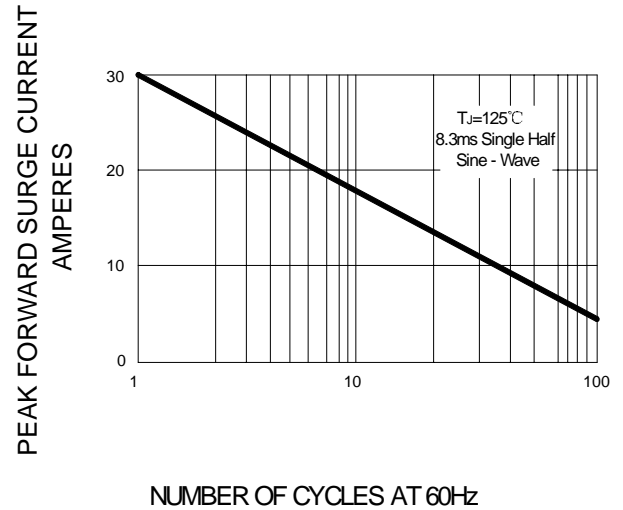
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

### Ratings AND Characteristic Curves

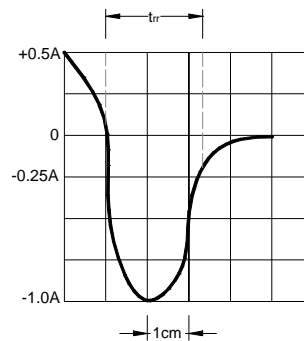
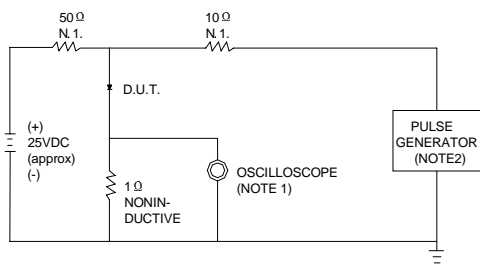
**FIG.1 – FORWARD DERATING CURVE**



**FIG.2 – PEAK FORWARD SURGE CURRENT**



**FIG.3 – TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC**



NOTES: 1. RISE TIME = 7ns MAX. INPUT IMPEDANCE = 1MΩ. 22pF.  
2. RISE TIME = 10ns MAX. SOURCE IMPEDANCE = 50 Ω.

SET TIME BASE FOR 50/100 ns/cm